



**Professional Ceramic Package Manufacturer
HE BEI SINOPACK ELECTRONIC TECH CO.,LTD.**





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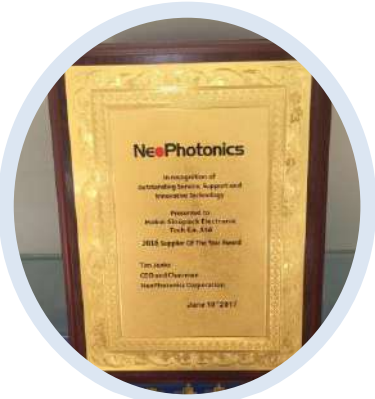
Sinopack



- ▶ The leader of ceramic packaging technology of China
- ▶ Established in Aug.2009 with registered capital 149 million RMB
- ▶ Committed to alumina ceramics, aluminum nitride ceramics and other materials, process research and development.
- ▶ Sinopack has a comprehensive grasp of manufacturing technology about multi-layer ceramic packages and substrates, and build several automatic production lines.
- ▶ It is equipped with advanced design instrumentalities such as high frequency, stress and thermal simulation, also established a complete testing technology platform for packages and substrates.
- ▶ Sinopack can provide professional solution for ceramic packaging which can meets the international standard.



- ★ Located in Shijiazhuang City, 300km south of Beijing
- ★ Workshop building : around 25000m² , including 6700m² clean room
- ★ The new plant is under construction which is 100 meters away from the current one



Neophotonics

2016

**Supplier of the
Year
Reward**



Lumentum

2017

**Excellence in value
innovation
Supplier**



Oplink

2018

**Business partner
Award**



Raycus

2019

**Best support
Award**



XGIGA

2019

**Excellent quality
Award**



Accelink

2020

**Delivery Support
Award**

ABOUT SINOPACK

Certificates

53 patents, including 10 invention patents and 43 utility model patent

<p>证书号第2842776号</p> <p>发明</p> <p>发明名称: 电子封装用陶瓷</p> <p>发明人: 丁东, 刘林杰, 李</p> <p>专利号: ZL 2015 1 075</p> <p>专利申请日: 2015年11月10</p> <p>专利权人: 河北中瓷电子科</p> <p>授权公告日: 2017年09月28</p> <p>局长 申长雨</p>	<p>证书号第2845007号</p> <p>发明</p> <p>发明名称: 高导热氮化硅陶瓷</p> <p>发明人: 赵东亮, 刘志平, 李</p> <p>专利号: ZL 2014 1 06385</p> <p>专利申请日: 2014年11月13</p> <p>专利权人: 河北中瓷电子科</p> <p>授权公告日: 2018年03月12</p> <p>局长 申长雨</p>	<p>证书号第2374930号</p> <p>发明</p> <p>发明名称: 电子封装用陶瓷</p> <p>发明人: 赵东亮</p> <p>专利号: ZL 2016 1 0</p> <p>专利申请日: 2016年03月</p> <p>专利权人: 河北中瓷电子科</p> <p>授权公告日: 2017年02月</p> <p>局长 申长雨</p>	<p>The United States of America</p> <p>Has received a new and useful invention. The title and description of the invention are enclosed. The requirements of law have been complied with, and it has been determined that a patent on the invention shall be granted under the law.</p> <p>Therefore, this</p> <p>United States Patent</p> <p>Grants to the person(s) having title to this patent the right to exclude others from making, using, offering for sale, or selling the invention throughout the United States of America, or importing the invention into the United States of America, and if the invention is a process, of the right to exclude others from using, offering for sale or selling throughout the United States of America, or importing into the United States of America, products made by that process, for the term set forth in 35 U.S.C. 154(a)(2) or (c)(1), subject to the payment of maintenance fees as provided by 35 U.S.C. 41(b). See the Maintenance Fee Notice on the inside of the cover.</p> <p>Joseph Matat</p> <p>Under Secretary of Commerce for Intellectual Property and Director of the United States Patent and Trademark Office</p>	<p>The United States of America</p> <p>Has received an application for a patent for a new and useful invention. The title and description of the invention are enclosed. The requirements of law have been complied with, and it has been determined that a patent on the invention shall be granted under the law.</p> <p>Therefore, this</p> <p>United States Patent</p> <p>Grants to the person(s) having title to this patent the right to exclude others from making, using, offering for sale, or selling the invention throughout the United States of America, or importing the invention into the United States of America, and if the invention is a process, of the right to exclude others from using, offering for sale or selling throughout the United States of America, or importing into the United States of America, products made by that process, for the term set forth in 35 U.S.C. 154(a)(2) or (c)(1), subject to the payment of maintenance fees as provided by 35 U.S.C. 41(b). See the Maintenance Fee Notice on the inside of the cover.</p> <p>Joseph Matat</p> <p>Under Secretary of Commerce for Intellectual Property and Director of the United States Patent and Trademark Office</p>	<p>证书号第1040794号</p> <p>实用新型专利证书</p> <p>实用新型名称: 光电发射模块外壳</p> <p>发明人: 孙晓明, 李军, 张义新, 郭志庆, 张炳军</p> <p>专利号: ZL 2010 2 0120831.8</p> <p>专利申请日: 2010年03月05日</p> <p>专利权人: 河北中瓷电子科</p> <p>授权公告日: 2010年10月20日</p> <p>局长 申长雨</p>	<p>证书号第1040794号</p> <p>实用新型专利证书</p> <p>实用新型名称: 光电发射模块外壳</p> <p>发明人: 孙晓明, 李军, 张义新, 郭志庆, 张炳军</p> <p>专利号: ZL 2010 2 0120831.8</p> <p>专利申请日: 2010年03月05日</p> <p>专利权人: 河北中瓷电子科有限公司</p> <p>授权公告日: 2010年10月20日</p> <p>局长 申长雨</p>	<p>证书号第1040794号</p> <p>实用新型专利证书</p> <p>实用新型名称: 光电发射模块外壳</p> <p>发明人: 孙晓明, 李军, 张义新, 郭志庆, 张炳军</p> <p>专利号: ZL 2010 2 0120831.8</p> <p>专利申请日: 2010年03月05日</p> <p>专利权人: 河北中瓷电子科有限公司</p> <p>授权公告日: 2010年10月20日</p> <p>局长 申长雨</p>
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ABOUT SINOPACK



PRODUCTION LINE OVERVIEW

www.sinopack.com.cn



ABOUT SINOPACK

Main Customers

Optic-Electronic Communication Device PKG	  	  	  	  
Wireless Communication Device PKG				
High Power Laser PKG				
Consumer Electronic Ceramic products				

Main Products

◆ Wireless Comm.Network

- ✓ Base Station
- ✓ Satellite Comm.

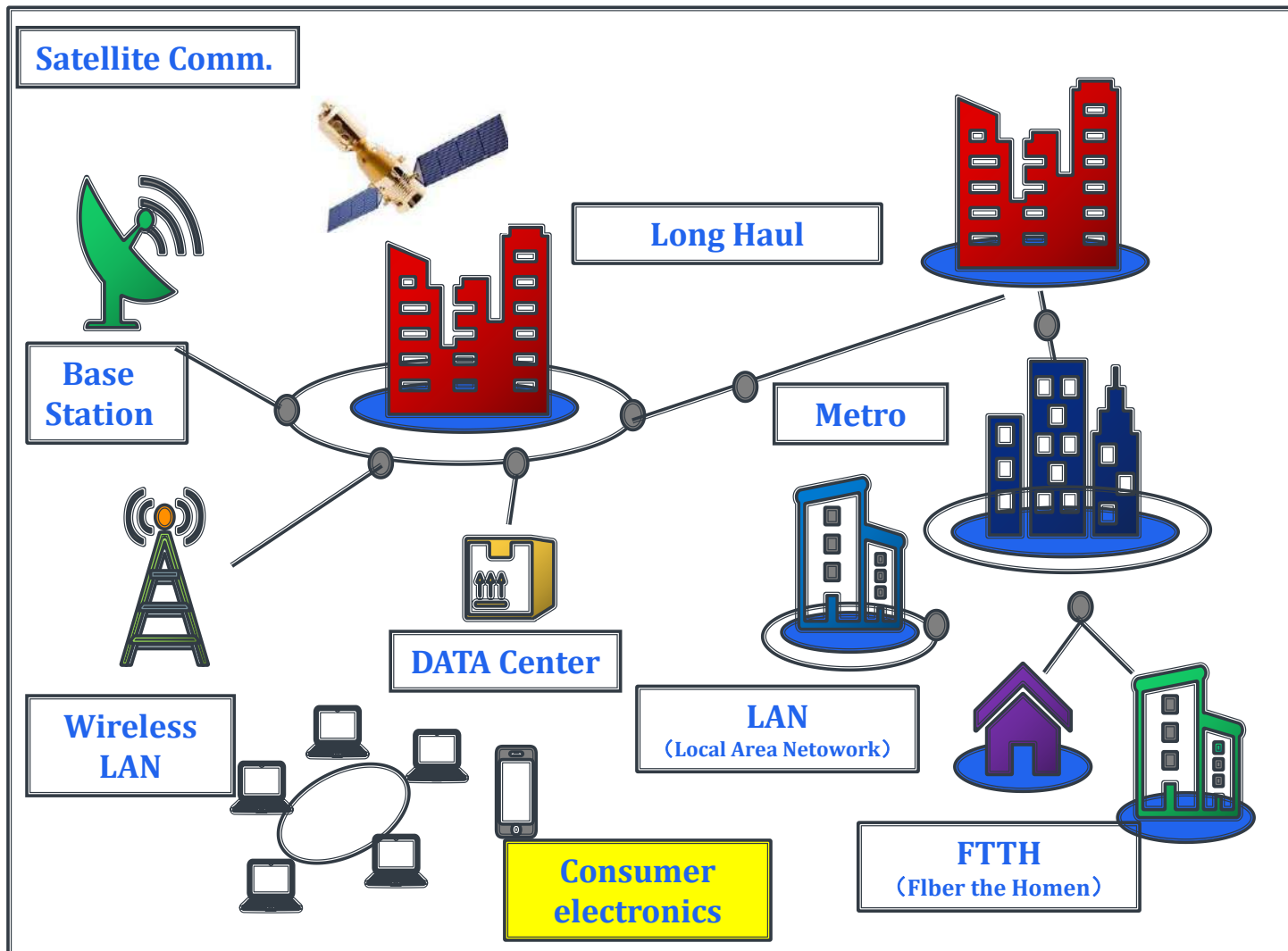
◆ Opt.Comm. Network

- ✓ DATA CENTER
- ✓ 局域网(LAN)
- ✓ 城域通信(Metro)
- ✓ 接入网(FTTX)
- ✓ 都市间长距离通信(Long Haul)

◆ Consumer Electronics

- ✓ 手机 cellphone
- ✓ 笔记本notebook
- ✓ 平板电脑tablet PC

End-Markets



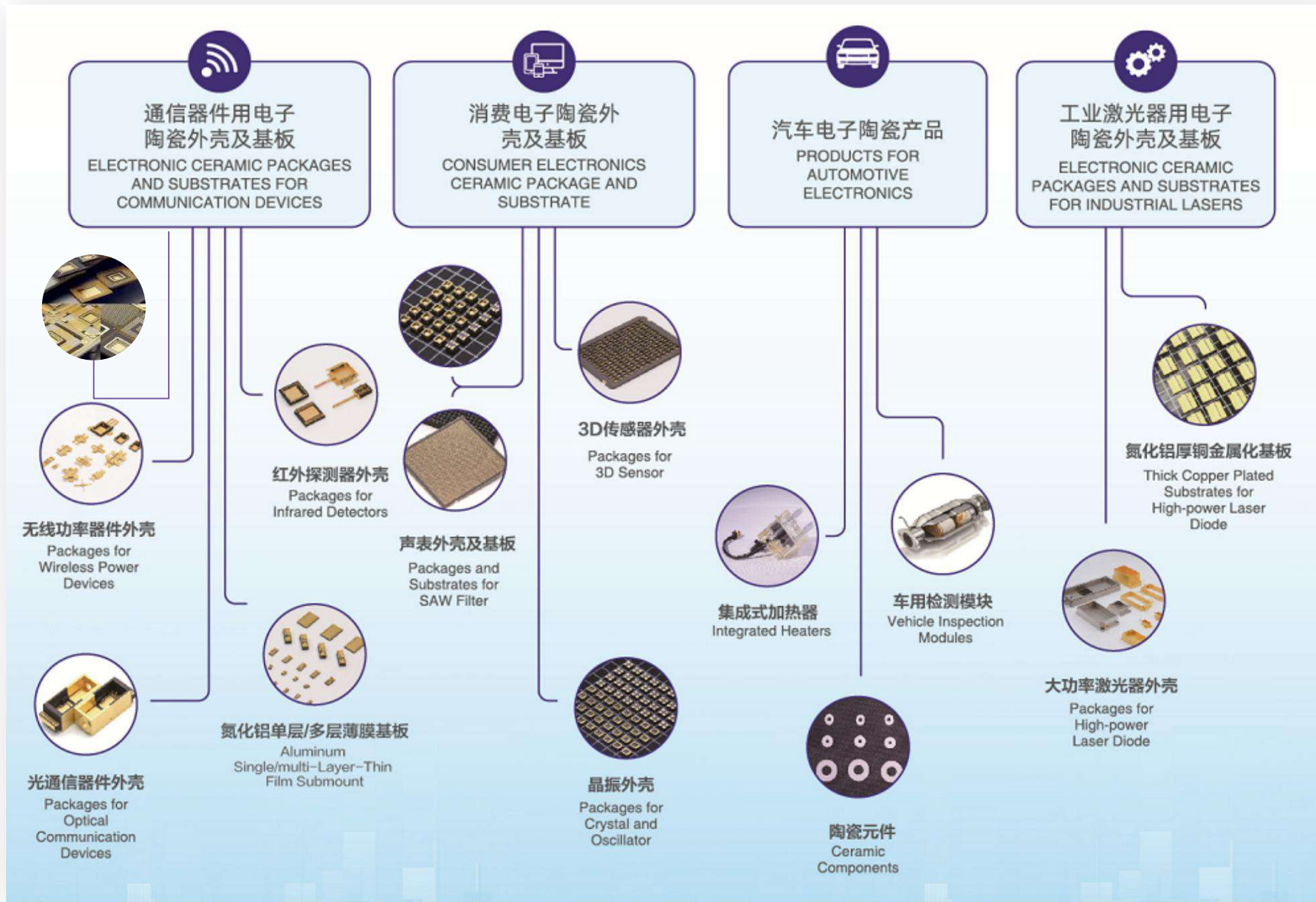
◆ High Power Laser Package



◆ Automotive Electronics

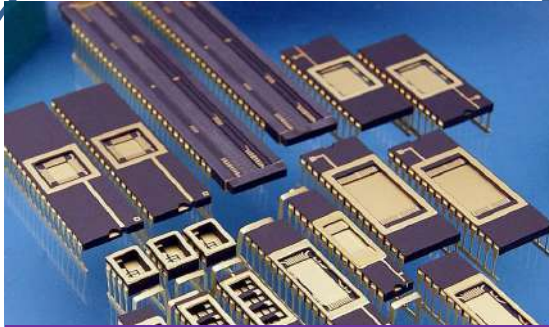


Main Products

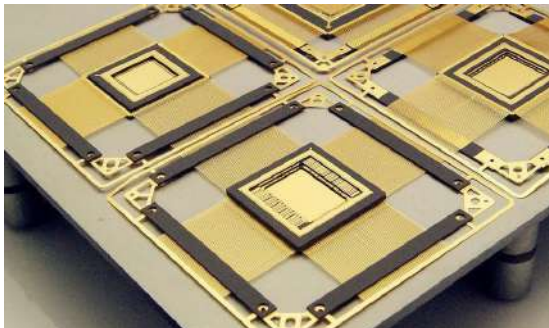


Product introduction

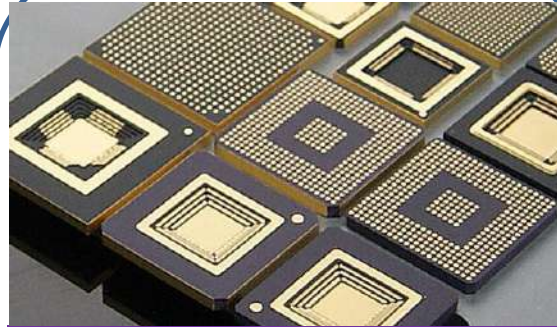
Integrated circuit Device package



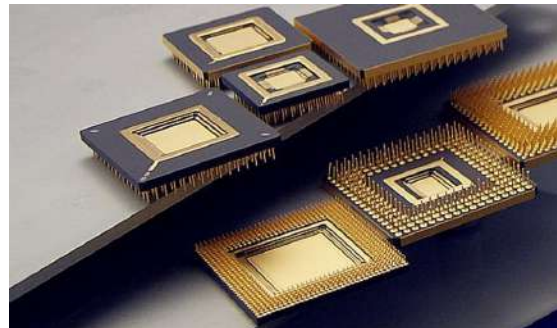
CDIP



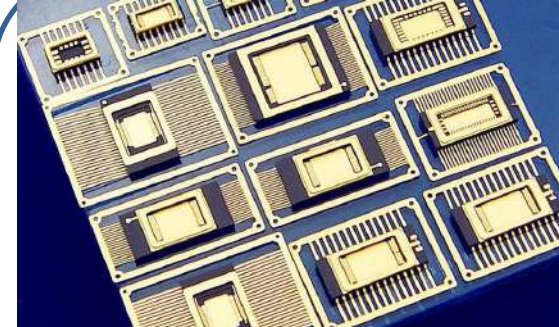
CQFP



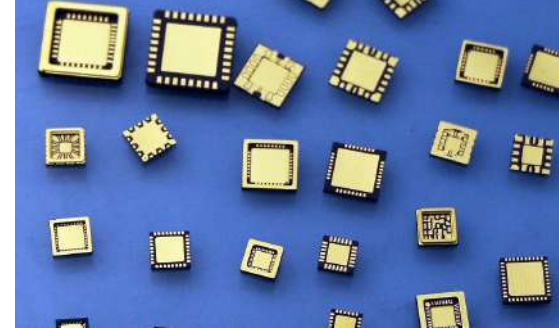
CLGA



CPGA



CSOP



LCC

Product introduction

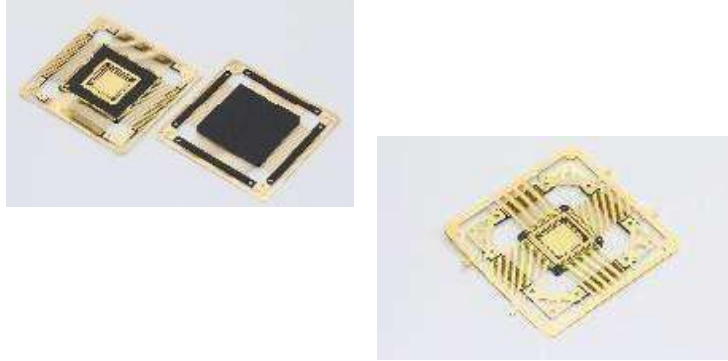
Integrated circuit Device package

CPGA



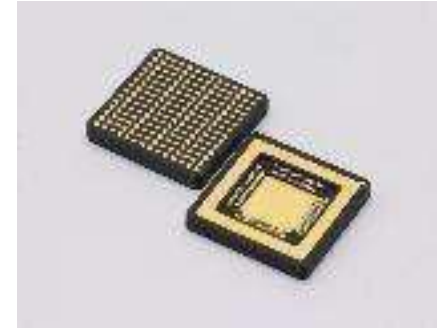
- Applied to digital Signal Processing
- Pluggable
- Pin: $\varnothing 0.46$, $\varnothing 0.25$
- Pitch: 2.54mm&1.27mm
- Frequency : DC~6GHz
- Sealing method : parallel seam sealing/Brazing
- Heat sink type :WCu/MoCu

CQFP



- Applied to digital Signal Processing
- Lead width: 0.20mm
- Pitch: 0.50mm
- Sealing method : parallel seam sealing/Brazing
- Heat sink type :WCu/MoCu

CLGA

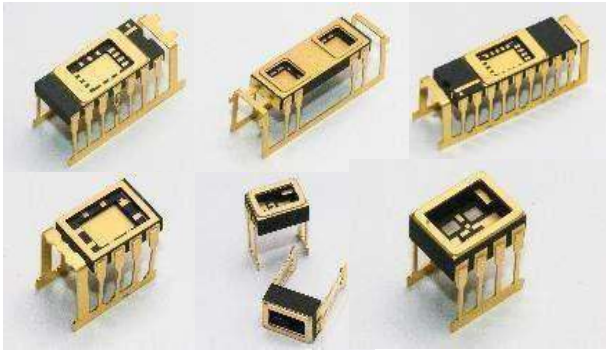


- Applied to digital Signal Processing
- Pad: $\varnothing 1.80\text{mm}$, $\varnothing 0.80\text{mm}$, $\varnothing 0.65\text{mm}$
- Pitch: 2.54mm, 1.27mm, 0.80mm
- Frequency : DC~6GHz
- Sealing method : parallel seam sealing/Brazing

Product introduction

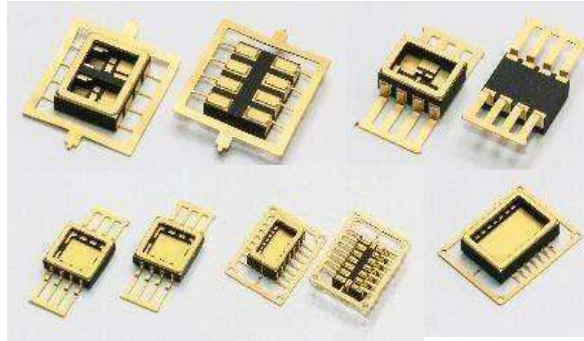
Integrated circuit Device package

CDIP



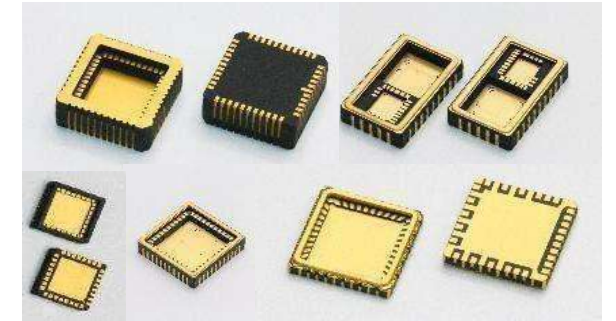
- Applied to Universal IC Package
Solid state relay, Digital isolator, ect;
- Ceramic: Al₂O₃ 90%(黑);
- Lead&Seal Ring : Kovar;
- Pitch: 2.54mm;
- Electrical properties :
- On-resistance : $\leq 1.0 \Omega$;
- Insulation resistance : $\geq 1 \times 10^{10} \Omega$, DC 500V;
- Sealing method : parallel seam sealing/Brazing ;

CSOP



- Applied to Universal IC Package
Solid state relay , Ldo , DC-DC, ect;
- Ceramic: Al₂O₃ 90%(黑)
- Lead&Seal Ring : Kovar
- Pitch: 2.54mm
- Electrical properties :
- On-resistance : $\leq 1.0 \Omega$;
- Insulation resistance : $\geq 1 \times 10^{10} \Omega$, DC 500V
- Sealing method : parallel seam sealing/Brazing

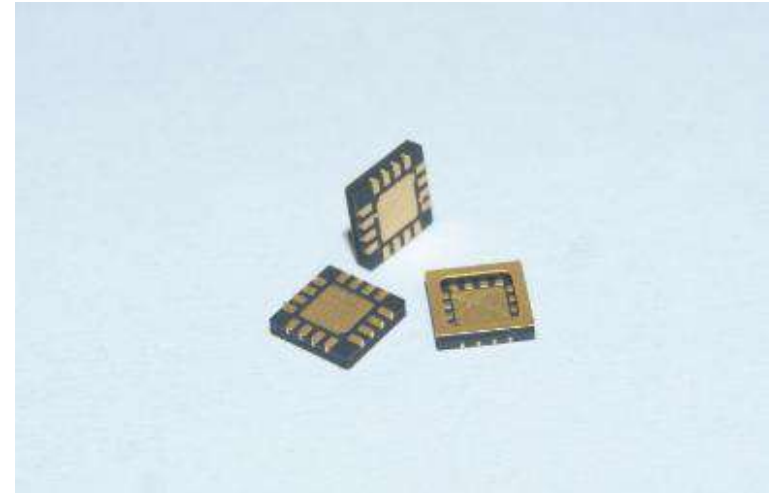
LCC



- Applied to Universal IC Package
- Ceramic: Al₂O₃ 90%(黑)
- Seal Ring : Kovar
- Pitch: 1.27mm, 0.80mm , 0.65mm
- Electrical properties :
- On-resistance : $\leq 0.5 \Omega$;
- Insulation resistance : $\geq 1 \times 10^{10} \Omega$, DC 500V
- Sealing method: parallel seam sealing/Brazing

Main Products

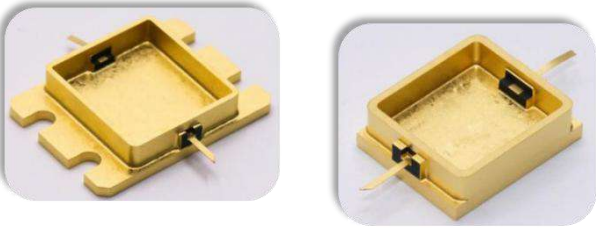
Wireless Power Device Packages



Product introduction

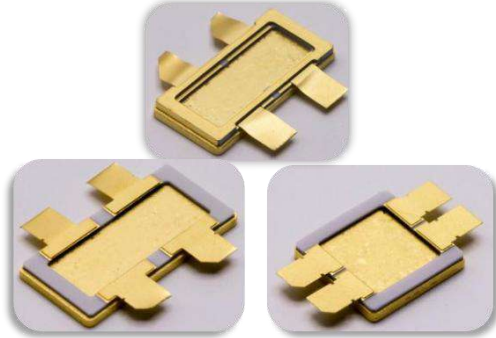
Package for Microwave module

Ceramic feedthrough power package



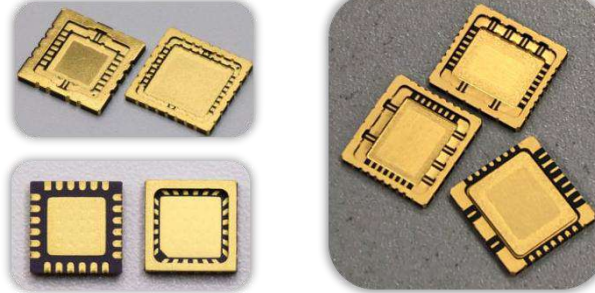
- 50 Ω port impedance
- Internal matching power device
- Frequency : DC~18GHz
- Sealing method : parallel seam sealing/Brazing /胶封gum
- Heat sink type : Cu/WCu/MoCu/CPC/CMC

Ceramic wall power package



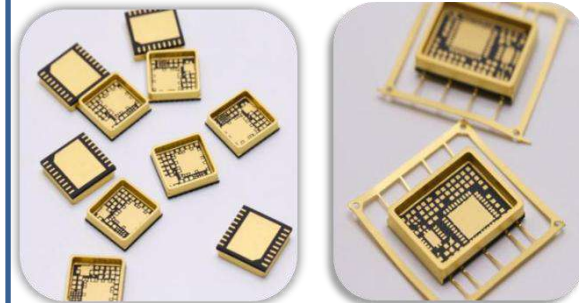
- Non-50 Ω port impedance (about 10 Ω)
- External/Pre-Matched Power Devices
- Frequency : DC~6GHz (依赖外匹配)
- Sealing method : parallel seam sealing/
Brazing / /胶封gum
- Heat sink type : Cu/WCu/MoCu/CPC/CMC

Ceramic Quad Flat No-lead Package



- 50 Ω port impedance
- For Power MMIC Package
- Frequency : DC~60GHz
- Sealing method : parallel seam sealing/Brazing /胶封gum
- Heat sink type : Al2O3/Cu/WCu/MoCu/CPC/CMC

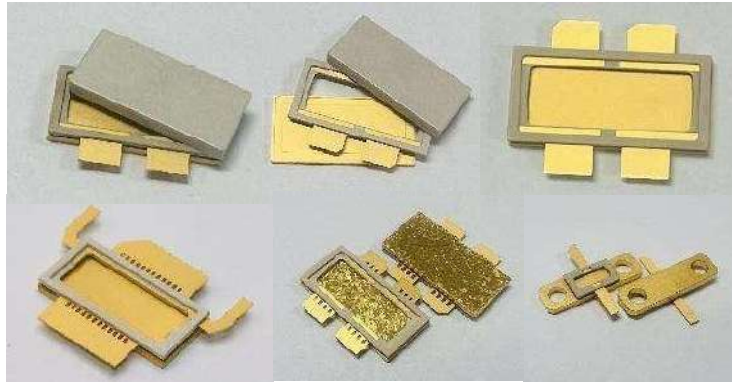
Metal wall type power package



- 50 Ω port impedance
- For MMIC or HIC Package
- Frequency : DC~32.5GHz
- Sealing method : parallel seam sealing/Brazing /胶封gum
- Heat sink type : Al2O3/Kovar

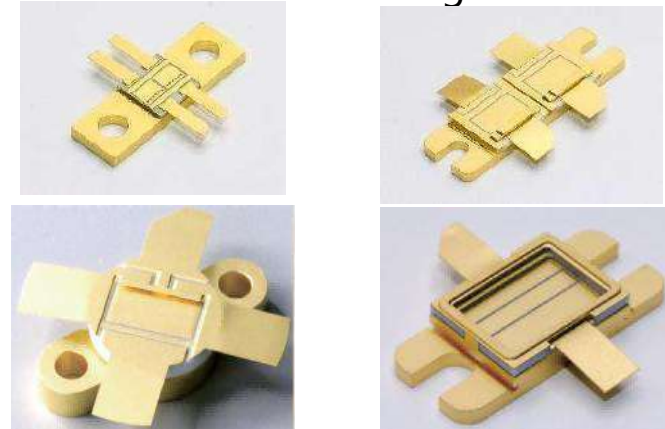
Product introduction

Adhesive, Plastic package



Material :
Frame - LCP ;
Heat sink -Cu、 CPC ect;
Lead - Cu ect ;
Glue -Epoxy glue ,
Curing condition : 180°C、 one hour ;
Airtightness : $\leq 1 \times 10^{-8}$ Pa.m³/s ;

Silicon Bipolar Transistor Package



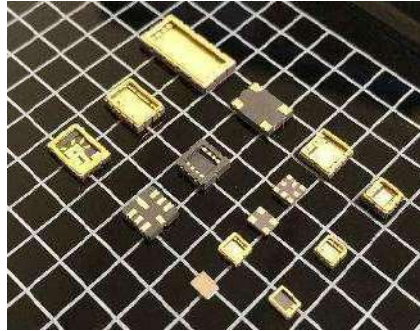
Material :
Heat sink- BeO ;
Base -WCu;
Lead - 4J34 ;
Frequency : P、 L、 S ,
Power : 200Wmax
Airtightness : Air tight $\leq 1 \times 10^{-9}$ Pa.m³/s , non air tight ;

Product introduction

Consumer Electronics Ceramic Package and Substrate

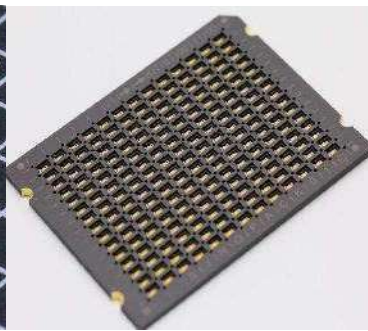
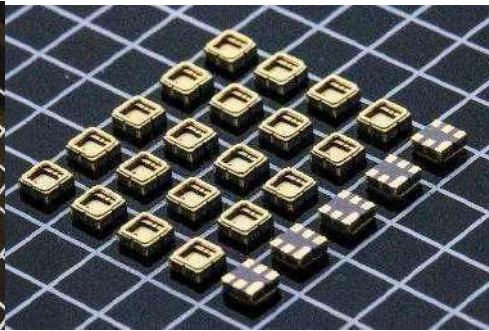
*Packages for Crystal
and Oscillator*

*Crystal Units
Crystal Oscillators*



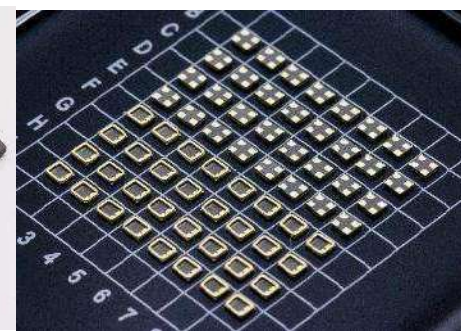
*Packages and SUBSubstrates
for SAW Filter*

*IF Filter/Resonator
RF Filter/Duplexers*



3D Sensor&CMOS

*Mobile camera module/
Smart City/Machine Vision/Security*



Customized&Miniaturization

1. 热敏晶体TSX
2. 温补振荡器TCXO
3. 音叉晶体TF

*High Accuracy & Wide
Temperature Range*

*Multi-layer Ceramic Structure
Temperature range(-40 to +125)*

High strength

*620MPa Ceramic
Bending Strength 650mpa*

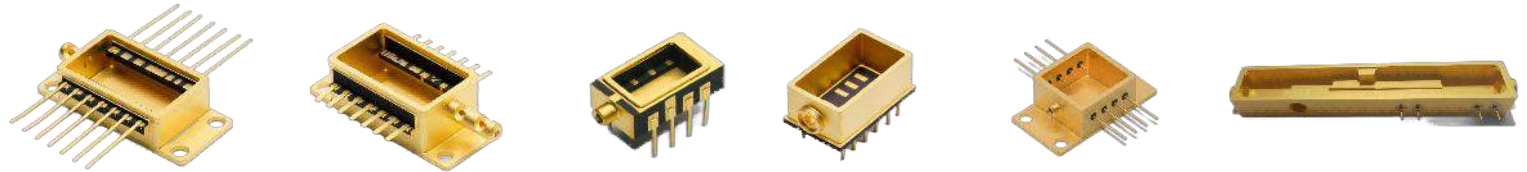
Product introduction

Optical Communication Devices Packages

*TOSA/ROSA
(2.5G/10G/4*25G/4*50G)*



*Butterfly/mini pin/Glass
Package*



*ICR-Intergrated coherent
transceiver*



*WSS-Wavelength selective
switch*

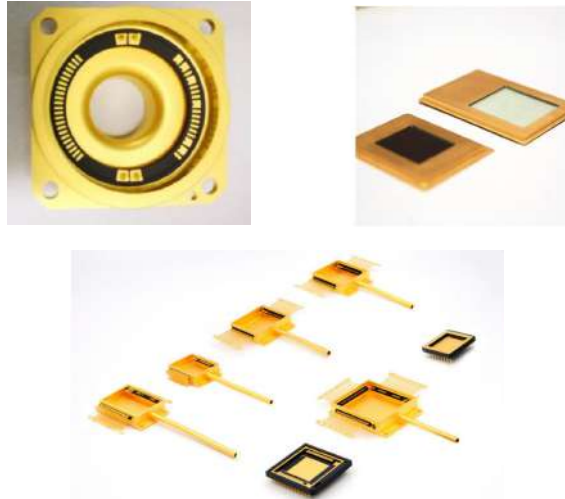


*Infrared Detectors Package
/TO*



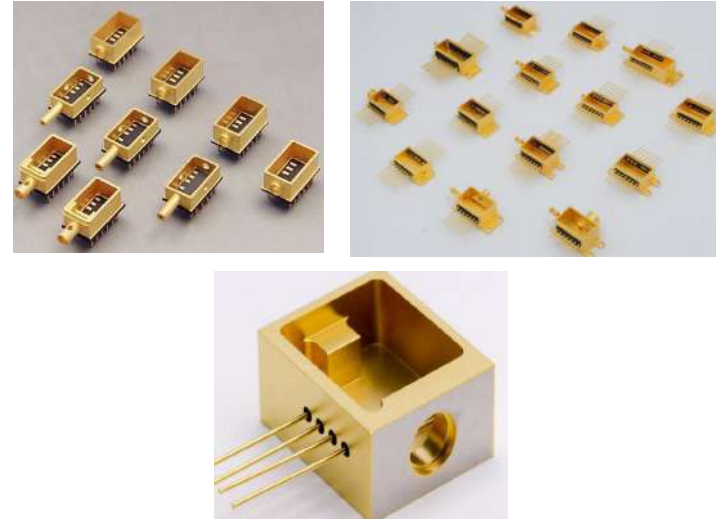
Product introduction

Infrared Detectors Package



Hermetic: $\leq 1 \cdot 10^{-9} \text{Pa} \cdot \text{m}^3/\text{S}$;
Lead Acount: 32, 36, 40, customized;
Base Material: WCu, Kovar, Al_2O_3 Ceramic;
Plating: Nickle plating, Gold plating;
Window: Sapphire, germanium, AR coating;

Butterfly and Glass Package



Hermetic: $\leq 1 \cdot 10^{-9} \text{Pa} \cdot \text{m}^3/\text{S}$;
Lead Acount: 8, 10, 14, customized;
Base Material: WCu, Kovar, Al_2O_3 Ceramic
, Glass;
Plating: Nickle plating, Gold plating;
Window: Sapphire, Glass;

Product introduction

Other PKG -SMD and TO

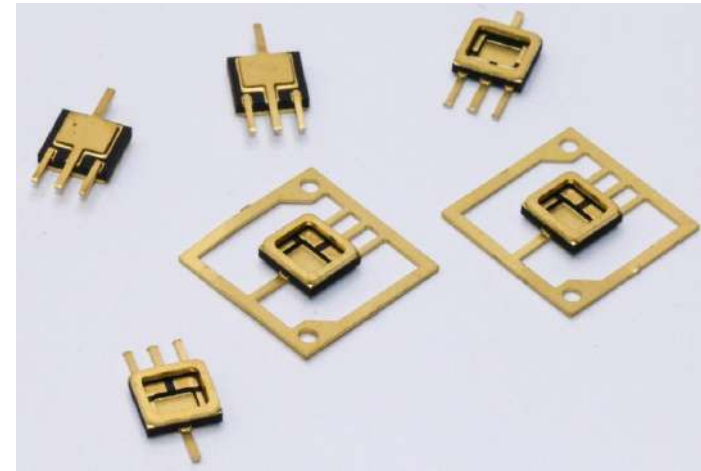


Type: SMD-2 , 1, 0.5, 0.2, 0.1

Material: Electrode-TU1;

Heat sink: WCu, MoCu, CMC, CPCetc;

Ceramic:Al₂ O₃ ;



Material:

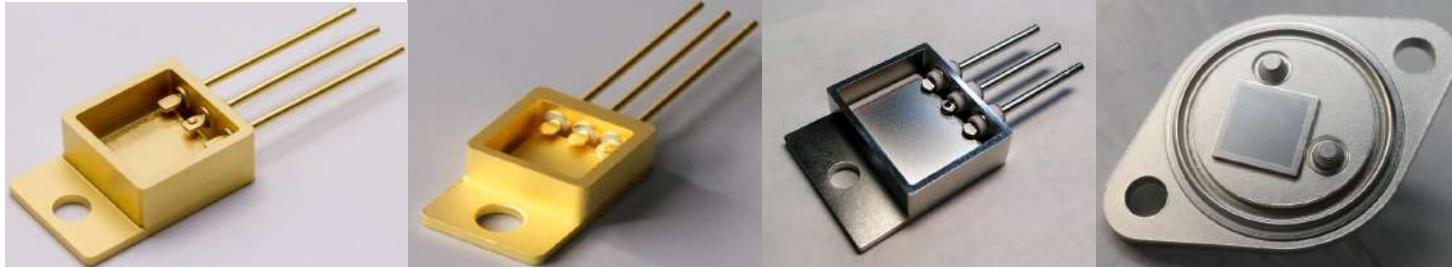
Frame-- 4J42、 4J34;

Ceramic--Al₂ O₃ ;

Lead: 4J34 ;

Product introduction

TO



Type: TO-3、 TO254、 TO257、
TO258 etc;

Material:

Base-: WCu, MoCu, TU1;

Heat sink: BeO;

Ceramic: Al₂ O₃ ;

Lead: 4J34, Kovar/Cu/Kovar;

Process capacity

www.sinopack.com.cn

PROCESS

Process Flow Chart

Material

Ceramic Material

characteristics

Metal Material

DESIGN

Designing for Construction Reliability

**Thermal simulation*

**Stress simulation*

Structure&wiring Design

**Structure design*

**RF&DC design*

☑ RF Simulation and measurement

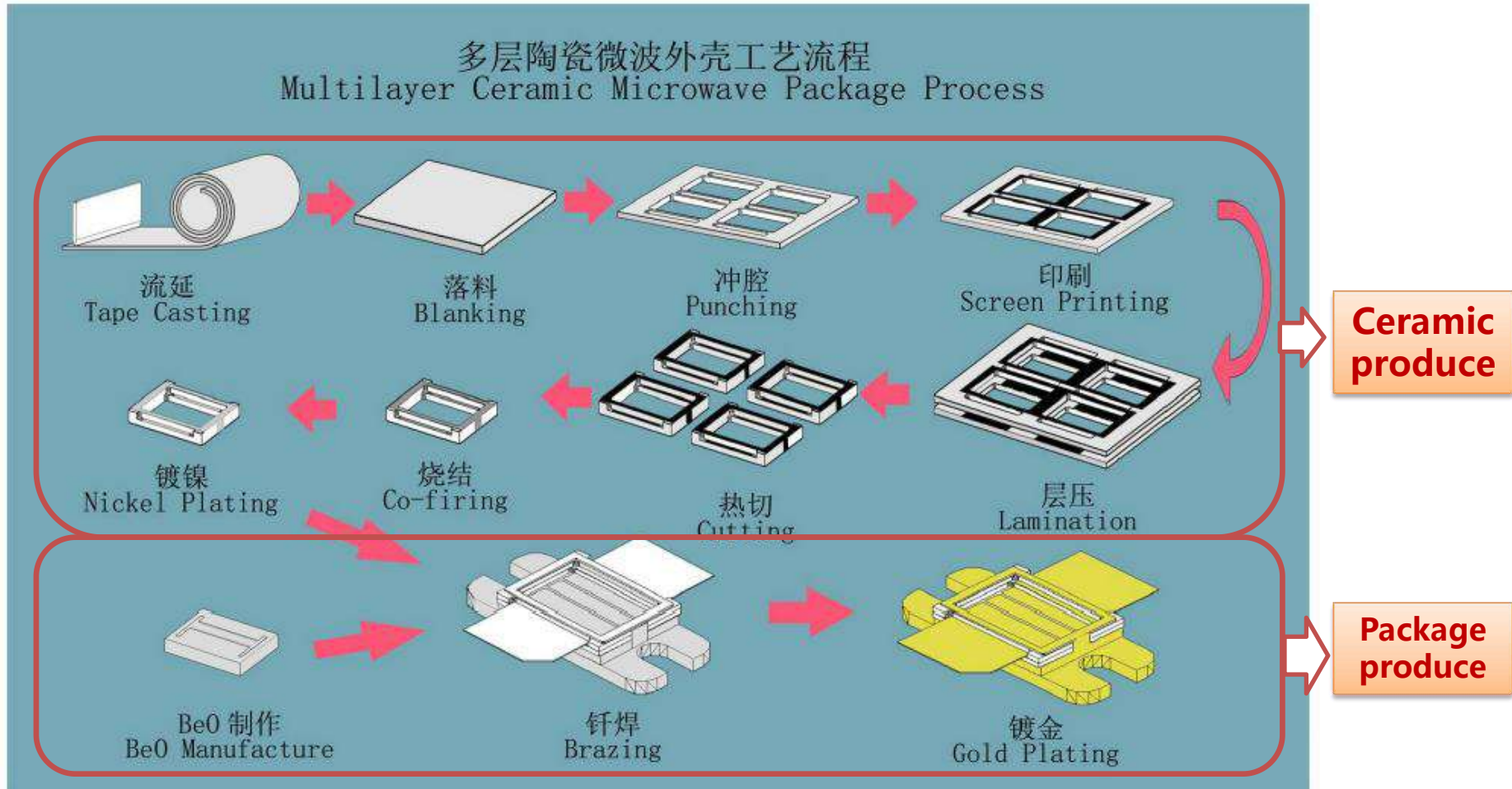
Quality

System

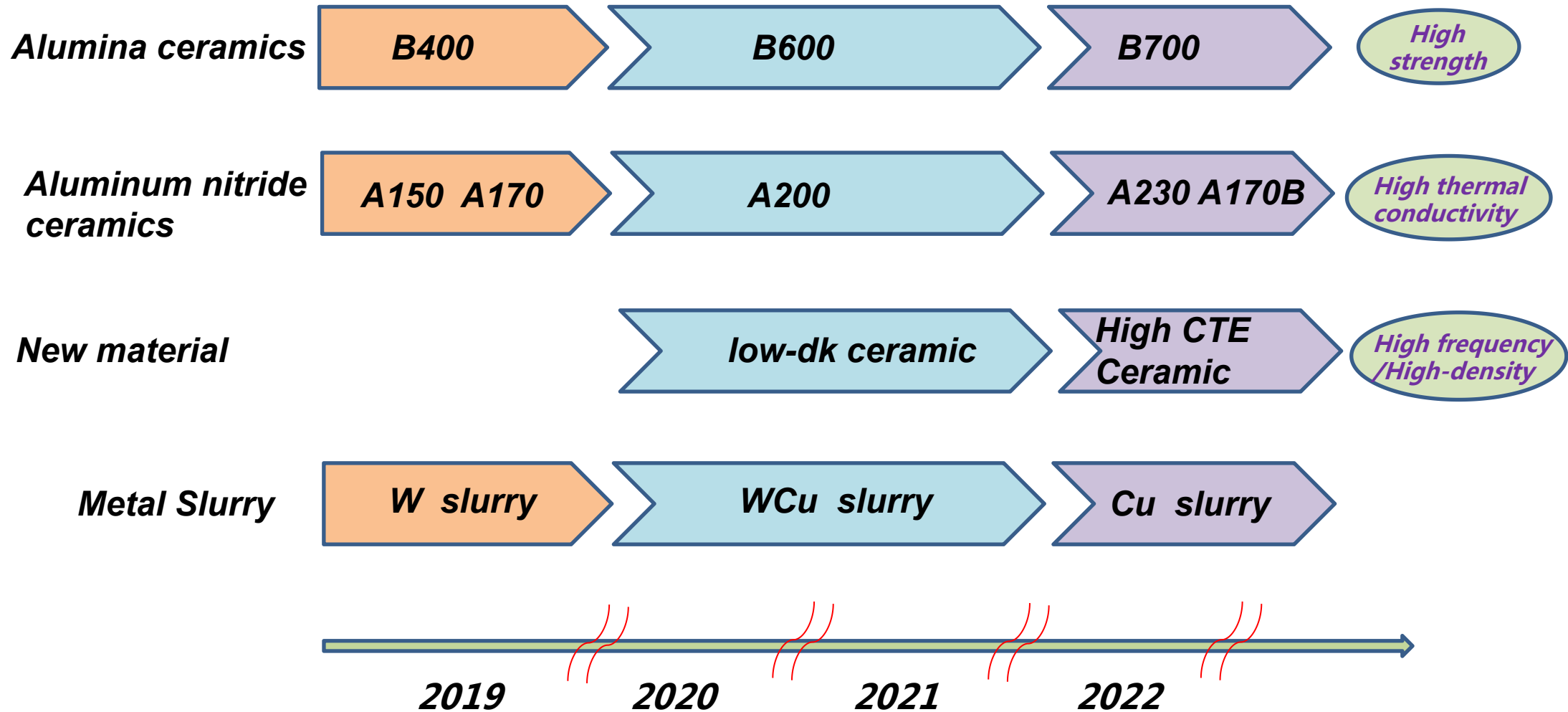
Test

Process capacity

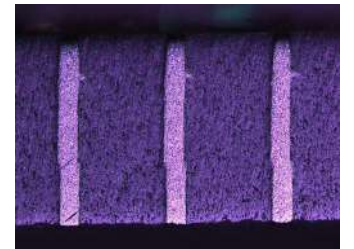
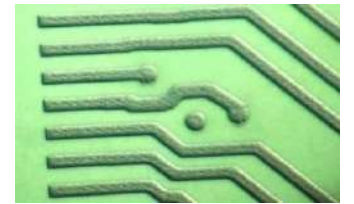
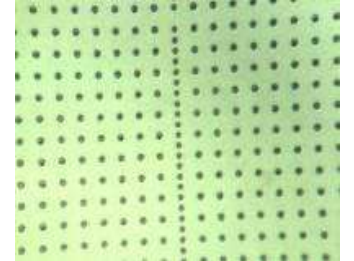
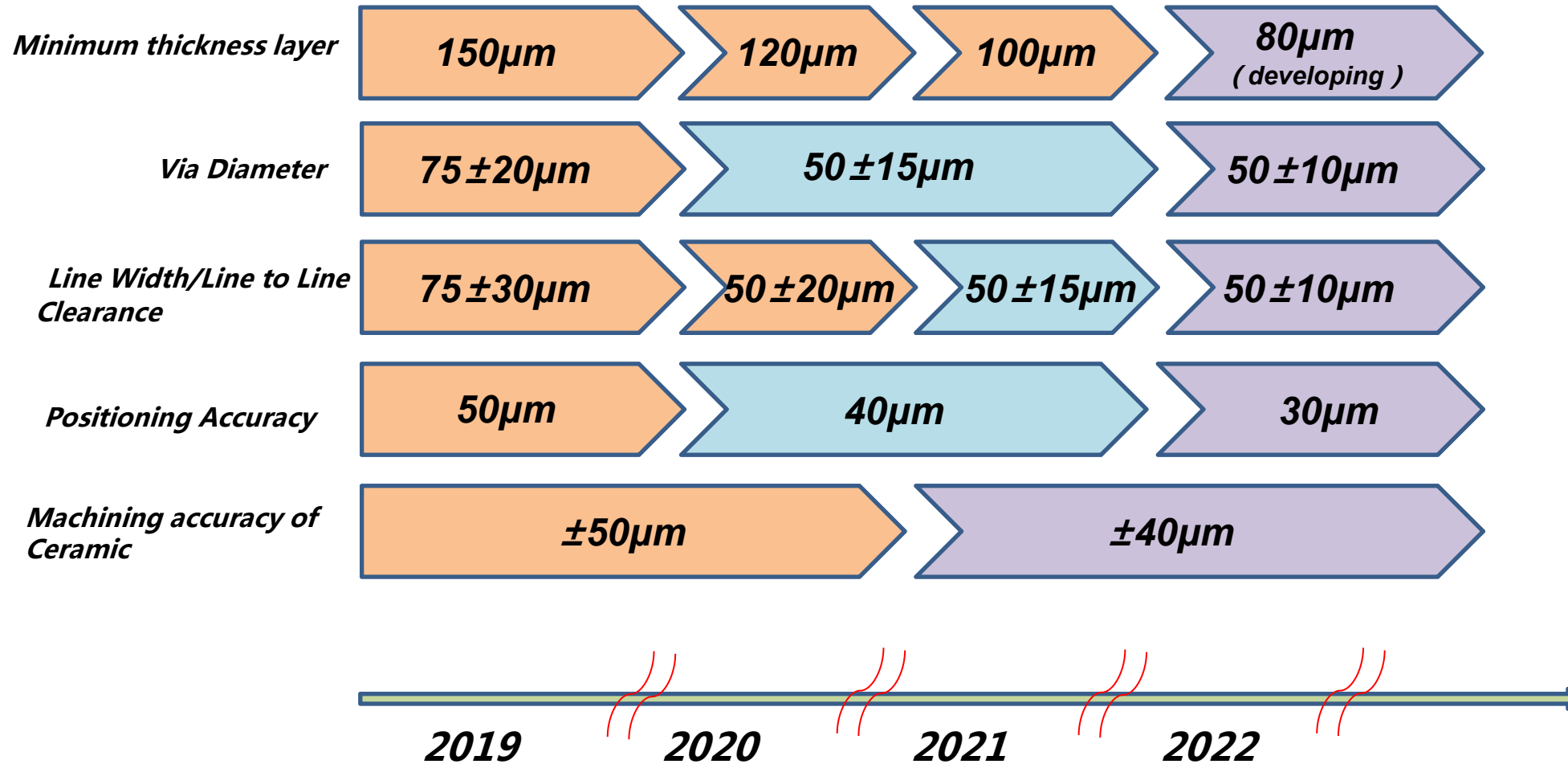
Process flow chart



2 Material parameter - Self-developed ceramic material




2 Process capacity - Manufacturing ability of ceramic

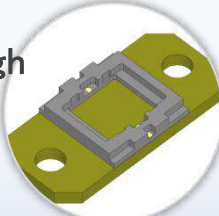


Simulation capability

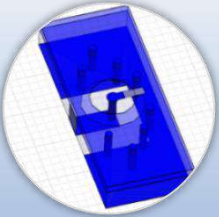
RF仿真



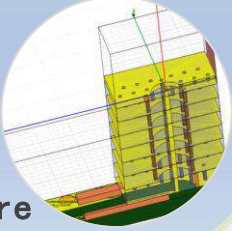
Feedthrough Structure



Complex Feedthrough Structure

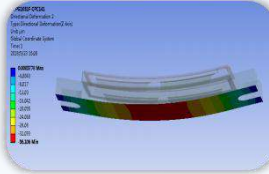


Vertical Transport Structure

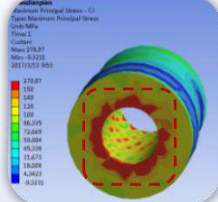


垂直传输结构
Complex Vertical Transport Structure

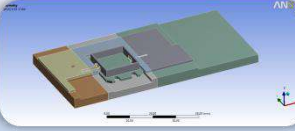
应力仿真



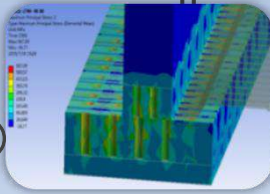
变形量
Deformation amount



焊接应力
welding stress

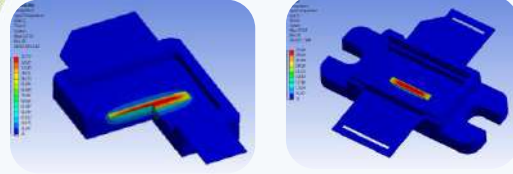


板级安装
Board-level installation

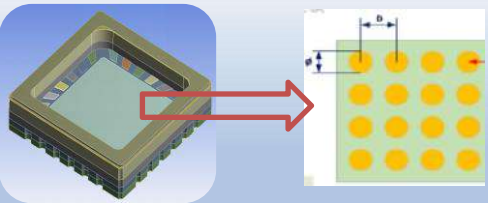


失效模式分析
Failure mode analysis (FMA)

热仿真



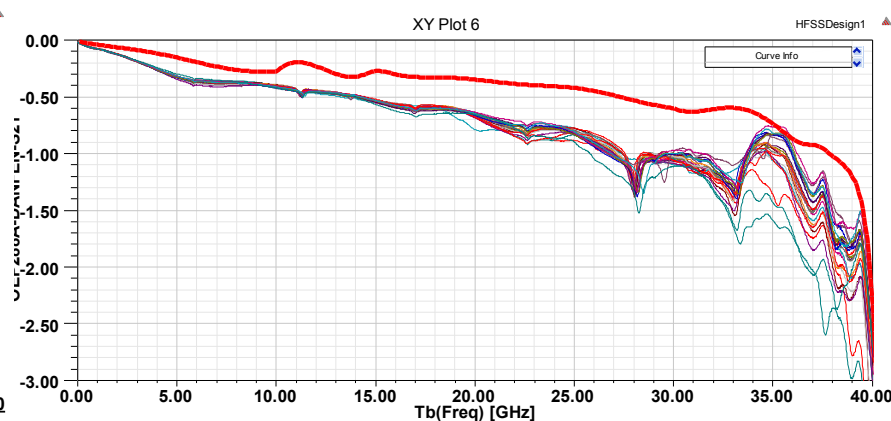
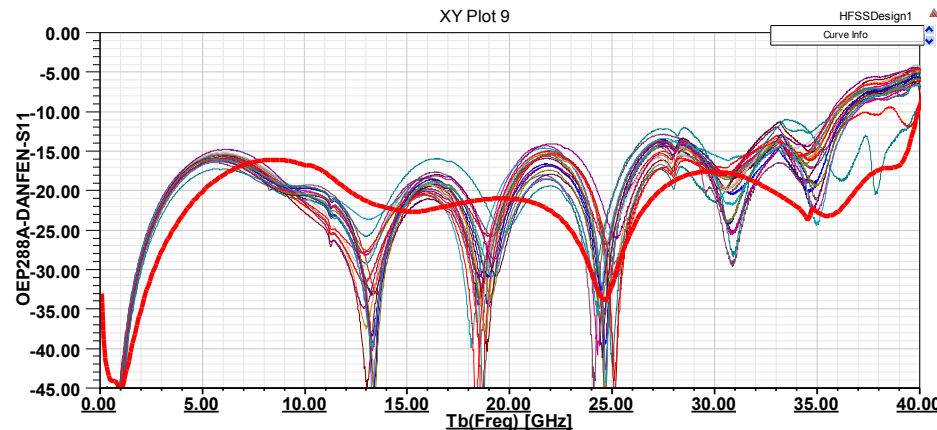
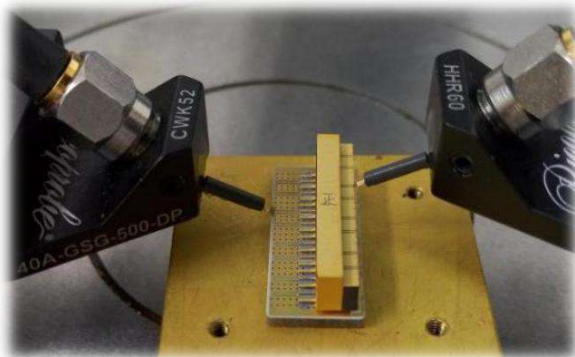
外壳热阻
Package thermal resistance



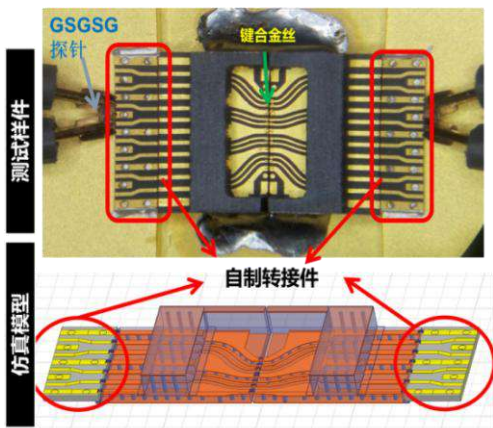
通孔热阻
Through hole thermal resistance

Simulation capability

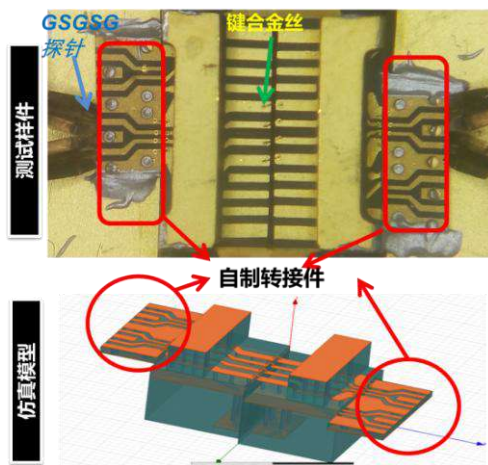
sample 1



Sample 2

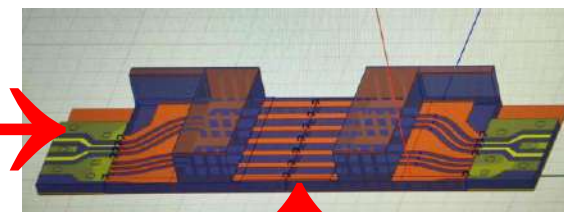


Sample 3



薄膜测试板替代PCB板

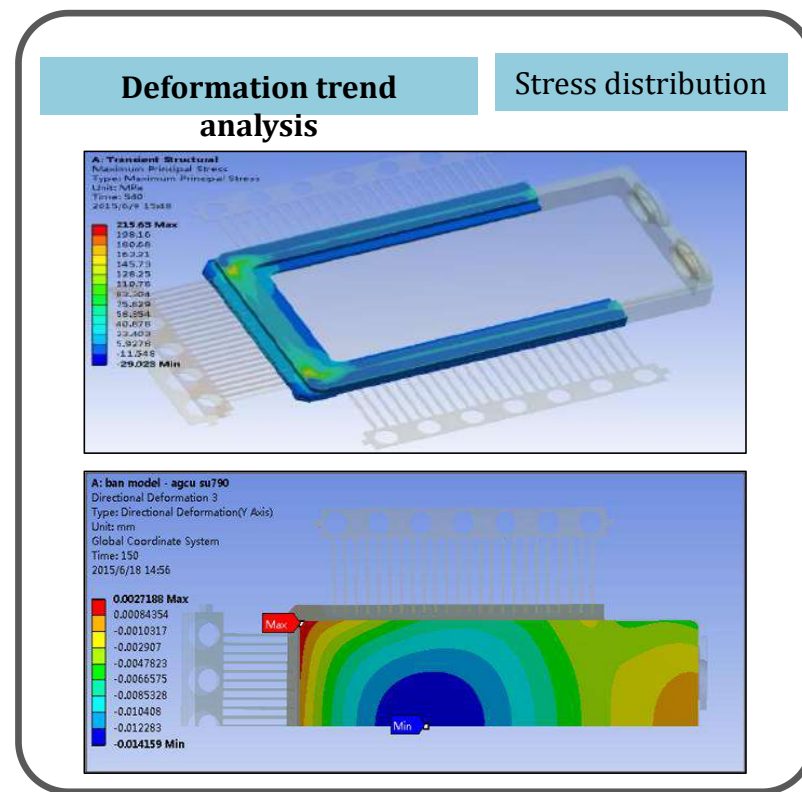
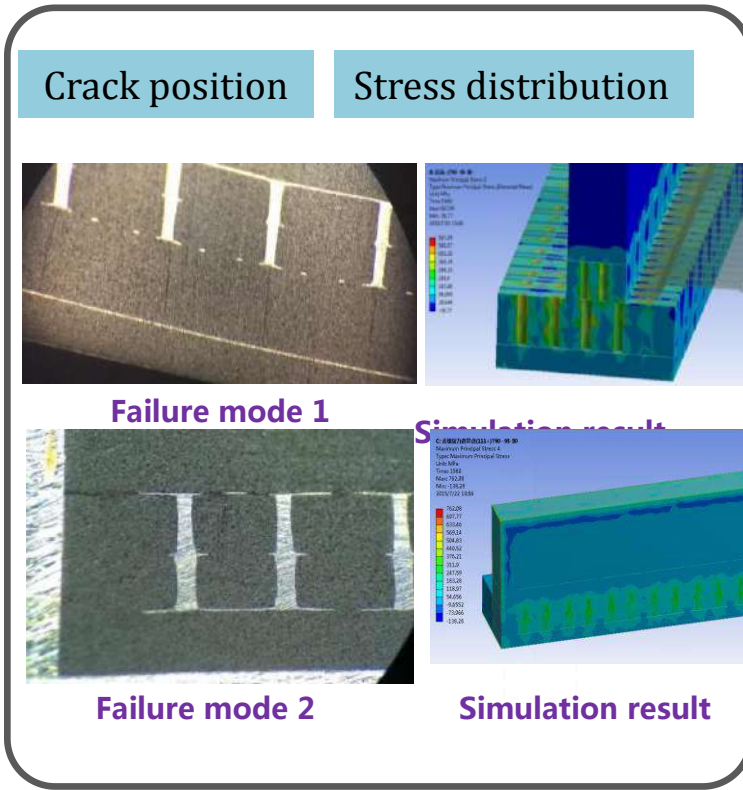
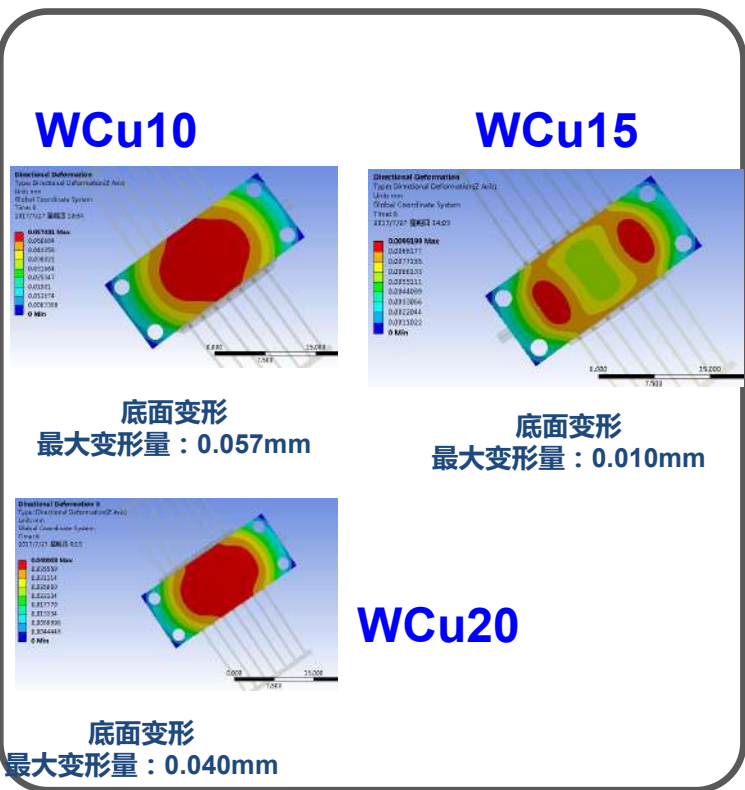
薄膜测试板



陶瓷件(pad to pad)

Simulation capability

FMEA(Failure Model Effectiveness Analysis)—瓷裂/变形

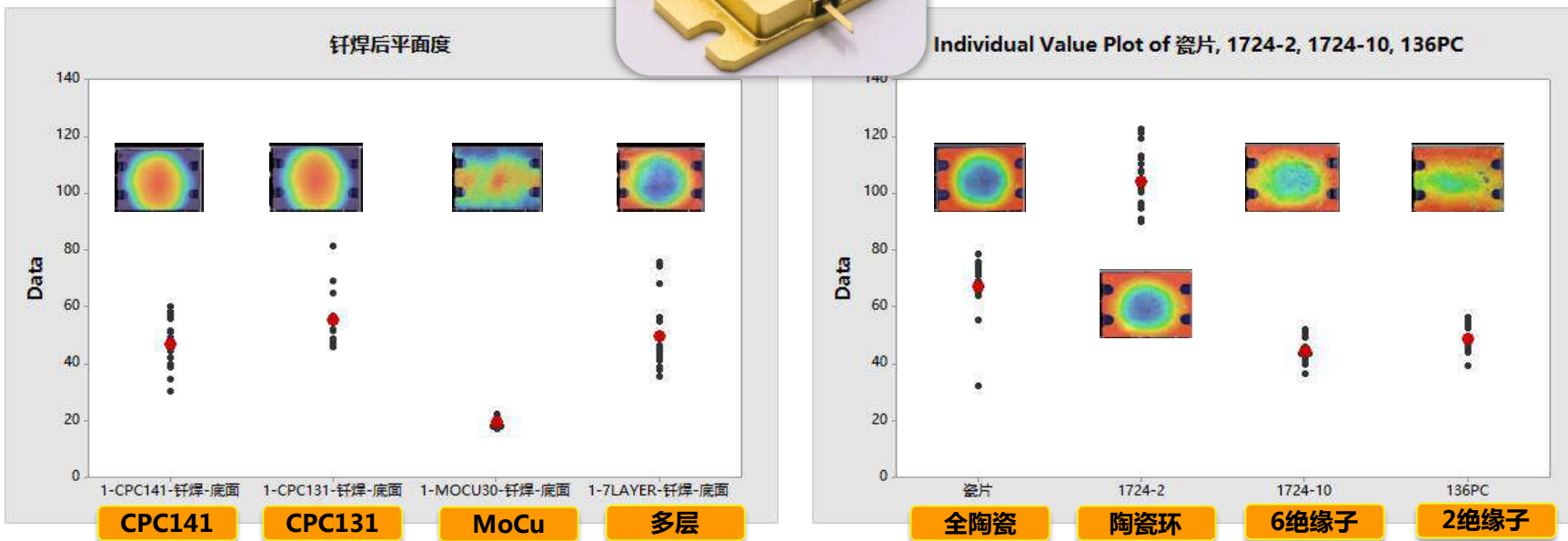


-weak position

Process capacity

Flatness control

- SINOPACK has structure matching design and verification test capability



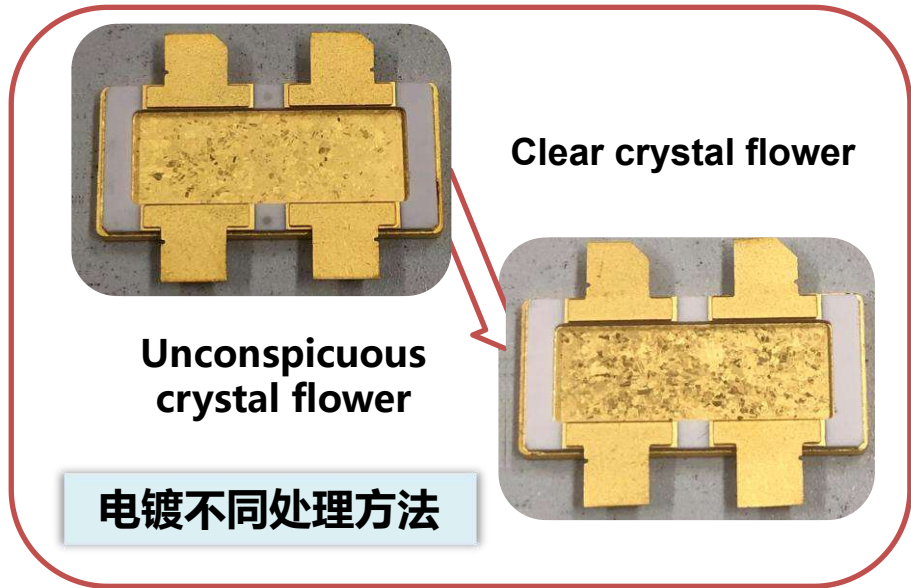
Comparison of flatness and plane deformation direction of the same package, different materials / machining methods

Comparison of flatness and deformation direction of different package structures in the same heat sink

Process capacity

Plating

- **Plating type : Ni-Au、Ni-Co-Au、Ni-Pd-Au.**
- **The plating meets the protection of different environment, has the processing ability of crystal flower, and meets the requirement of solderability of different plating.**



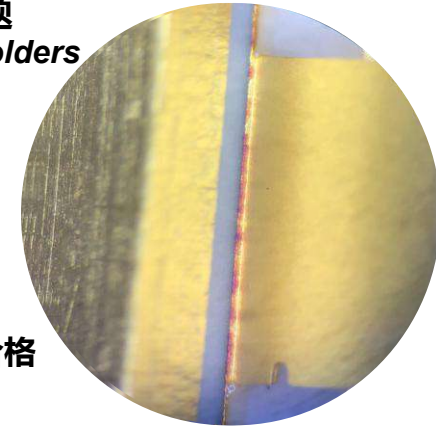
		1	2	3	4	5	Avg.
芯区粗糙度对比(μm)	晶花明显	0.47	0.48	0.52	0.42	0.51	0.48
	晶花不明显	0.50	0.51	0.53	0.50	0.48	0.50

Plating protection

AgCu焊料变色问题
Discoloration of AgCu solders

镀层致密处理工艺

经过1000h高温高湿试验合格
Passed 1000h high temperature and high humidity test



质量-体系

Certificate of Registration



兹证明

河北中瓷电子科技股份有限公司
河北省石家庄市鹿泉区经济开发区昌盛大街21号C2厂房

的质量管理体系适用于

加热器、传感器、线束、电子封装外壳及基板的生产

已经 NQA 根据标准
IATF 16949 : 2016
(删减产品设计)

审核和注册

本注册要求组织必须按照上述标准保持其质量管理体系，并由 NQA 进行监督。
若有任何疑问，以英文证书为准



Managing Director



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NQA Certificate No: T 81960
IATF Certificate No: 0344223
Date: 26 November 2018
Valid Until: 25 November 2021
Version: 2



Issue 5

IATF16949




注册号: 01216Q30824R2M
颁证日期: 2016.11.04
有效期至: 2019.10.15
换证日期: 2018.09.21



质量管理体系认证证书

(正本)
兹证明

河北中瓷电子科技股份有限公司

统一社会信用代码: 91130185693456472R
注册地址: 石家庄市鹿泉经济开发区昌盛大街21号

已按照
GB/T 19001-2016 idt ISO 9001:2015
标准要求建立并实施了质量管理体系。
该管理体系适用于

**电子封装外壳及基板、陶瓷元件、车用加热器的研
生产和销售**

涉及的场所及相关活动:

场所地址	场所邮编	场所主要活动
河北省石家庄市鹿泉经济开发区昌盛大街21号C2厂房	050200	电子封装外壳及基板、陶瓷元件、车用加热器的研发、生产和销售



中国认可
国际互认
管理体系
MANAGEMENT SYSTEM
CNAS C012-M




注册号: 01216E20741R2M
颁证日期: 2016.10.13
有效期至: 2019.10.12
换证日期: 2017.09.19



环境管理体系认证证书

(正本)
兹证明

河北中瓷电子科技股份有限公司

统一社会信用代码: 91130185693456472R
注册地址: 石家庄市鹿泉经济开发区昌盛大街21号

已按照
GB/T 24001-2016 idt ISO 14001:2015
标准要求建立并实施了环境管理体系。
该管理体系适用于

**电子封装外壳及基板、陶瓷元件、车用加热器的研
生产和销售**

涉及的场所及相关活动:

场所地址	场所邮编	场所主要活动
河北石家庄市鹿泉经济开发区昌盛大街21号(总部)	050200	电子封装外壳及基板、陶瓷元件、车用加热器的研发、生产和销售
河北石家庄市合作路113号	050051	电子封装外壳的生产和销售



中国认可
国际互认
管理体系
MANAGEMENT SYSTEM
CNAS C012-M




注册号: 01216S20704R2M
颁证日期: 2016.09.29
有效期至: 2019.09.28



职业健康安全管理体系 认证证书

(正本)
兹证明

河北中瓷电子科技股份有限公司

组织机构代码: 69345647-2
注册地址: 石家庄市鹿泉经济开发区昌盛大街21号

已按照
GB/T 28001-2011 (OHSAS 18001:2007, IDT)
标准要求建立并实施了职业健康安全管理体系。
该管理体系适用于

**电子封装外壳及基板、陶瓷元件、车用加热器的研发、
生产和销售**

涉及的场所及相关活动:

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河北石家庄市鹿泉经济开发区昌盛大街21号(总部)	050200	电子封装外壳及基板、陶瓷元件、车用加热器的研发、生产和销售
河北石家庄市合作路113号	050051	电子封装外壳的生产和销售



中国认可
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管理体系
MANAGEMENT SYSTEM
CNAS C012-M

ISO9001

ISO14001

OHSAS18001

Quality / Reliability Test Items

序号	可靠性测试项目
1	visual inspection 外观检验
2	Electrical property 电性能
3	Hermeticity 气密性
4	Dimension 尺寸
5	Plating thickness 镀层厚度
6	Quality of Gold Plating 镀层质量
7	Lead integrity 引线牢固性

序号	可靠性测试项目
8	Bond Strength 键合拉力
9	Die Shear Strength 芯片剪切力
10	Temperature cycling 温度循环
11	Thermal Shock 热冲击
12	Mechanical Shock 机械冲击
13	Vibration 扫频振动

** 1~7 is applicable to all products inspection*

** 1~13 is suitable for internal control inspection of newly developed products*

** 8~13 are periodic inspection of mass production, semi-annually*

All experimental methods were based on MIL883

Quality



温度循环



三维测量仪器



检漏



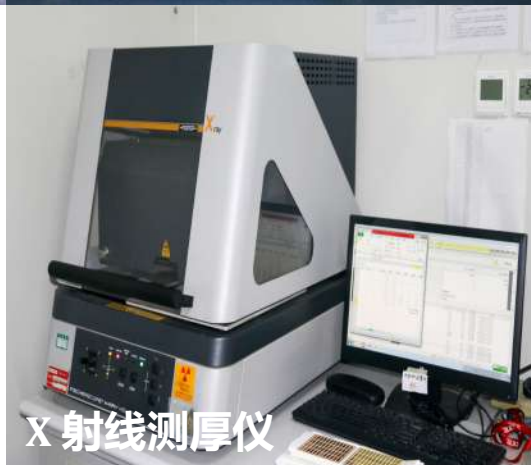
拉力测试



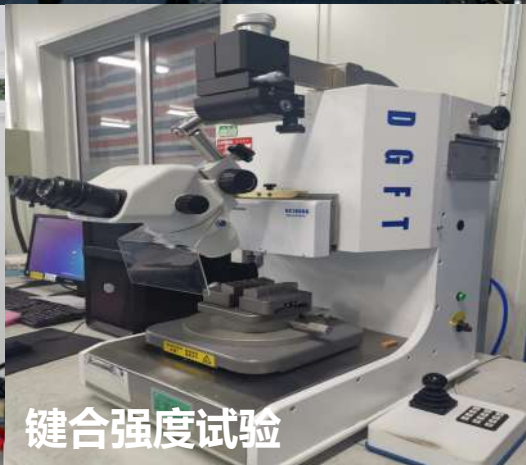
飞针试验台



X 射线透视



X 射线测厚仪



键合强度试验



T H A N K S